



CPH6122

Bipolar Transistor -30V, -3A, Low VCE(sat), PNP Single CPH6

ON Semiconductor®

<http://onsemi.com>

Applications

- Relay drivers, lamp drivers, motor drivers, flash

Features

- Adoption of MBIT process
- High current capacitance
- Low collector-to-emitter saturation voltage
- High-speed switching
- Ultrasmall package facilitates miniaturization in end products (mounting height : 0.9mm)
- High allowable power dissipation

Specifications

Absolute Maximum Ratings at Ta=25°C

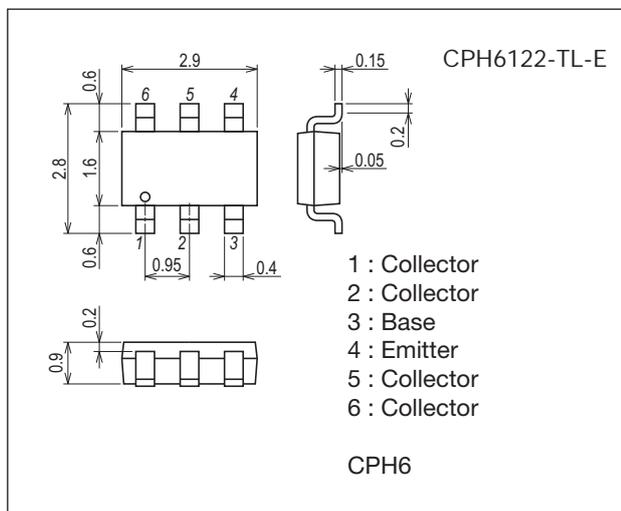
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CB0}		-30	V
Collector-to-Emitter Voltage	V _{CEO}		-30	V
Emitter-to-Base Voltage	V _{EB0}		-5	V
Collector Current	I _C		-3	A
Collector Current (Pulse)	I _{CP}		-5	A
Base Current	I _B		-600	mA
Collector Dissipation	P _C	Mounted on a ceramic board (600mm ² ×0.8mm)	1.3	W
Junction Temperature	T _j		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ)

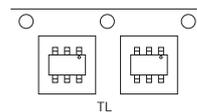
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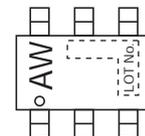
Product & Package Information

- Package : CPH6
- JEITA, JEDEC : SC-74, SOT-26, SOT-457
- Minimum Packing Quantity : 3,000 pcs./reel

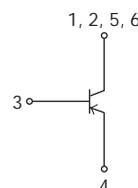
Packing Type: TL



Marking



Electrical Connection

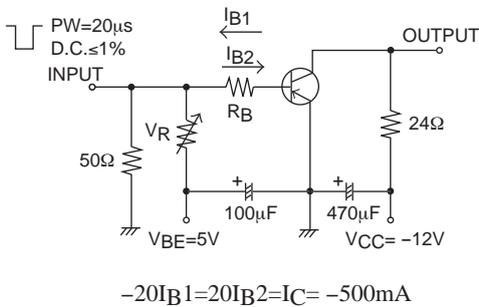


CPH6122

Electrical Characteristics at $T_a=25^\circ\text{C}$

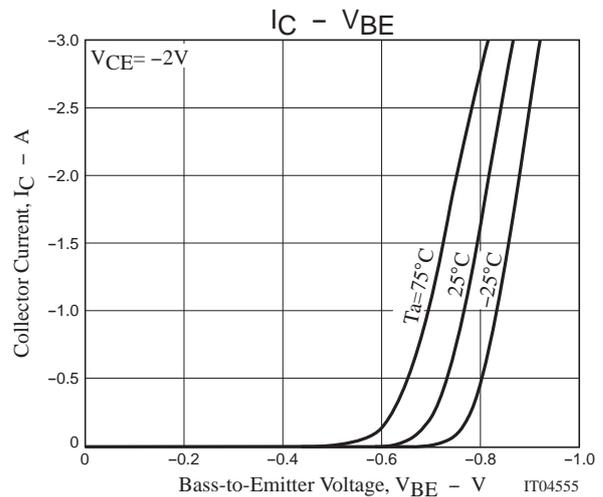
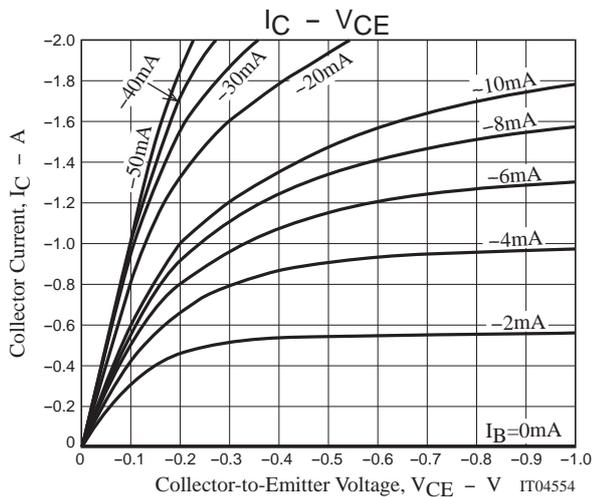
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB} = -30\text{V}, I_E = 0\text{A}$			-0.1	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB} = -4\text{V}, I_C = 0\text{A}$			-0.1	μA
DC Current Gain	h_{FE}	$V_{CE} = -2\text{V}, I_C = -500\text{mA}$	200		560	
Gain-Bandwidth Product	f_T	$V_{CE} = -10\text{V}, I_C = -500\text{mA}$		400		MHz
Output Capacitance	C_{ob}	$V_{CB} = -10\text{V}, f = 1\text{MHz}$		25		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)1}$	$I_C = -1.5\text{A}, I_B = -30\text{mA}$		-180	-270	mV
	$V_{CE(sat)2}$	$I_C = -1.5\text{A}, I_B = -75\text{mA}$		-120	-180	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = -1.5\text{A}, I_B = -30\text{mA}$		-0.83	-1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = -10\mu\text{A}, I_E = 0\text{A}$	-30			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = -1\text{mA}, R_{BE} = \infty$	-30			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = -10\mu\text{A}, I_C = 0\text{A}$	-5			V
Turn-On Time	t_{on}	See specified Test Circuit.		50		ns
Storage Time	t_{stg}			270		ns
Fall Time	t_f			27		ns

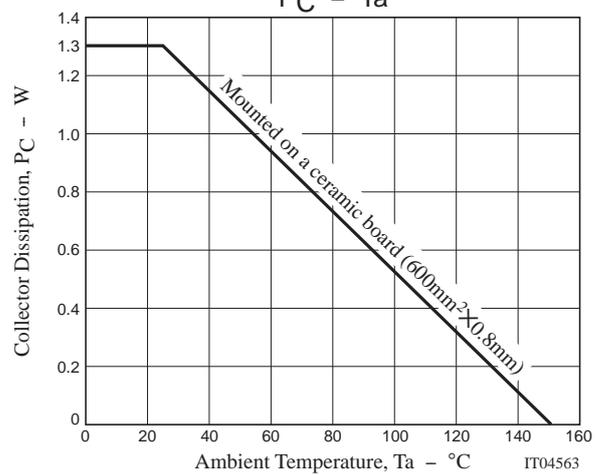
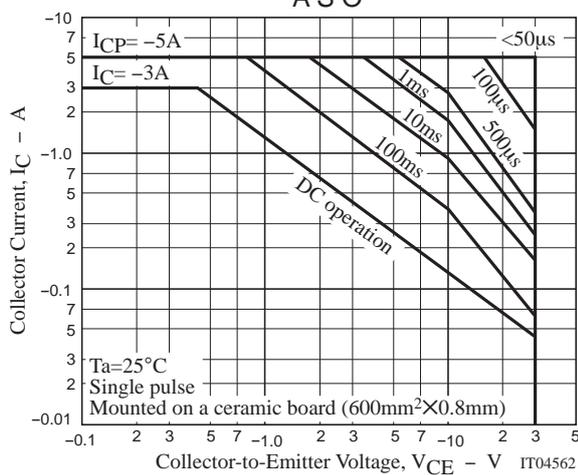
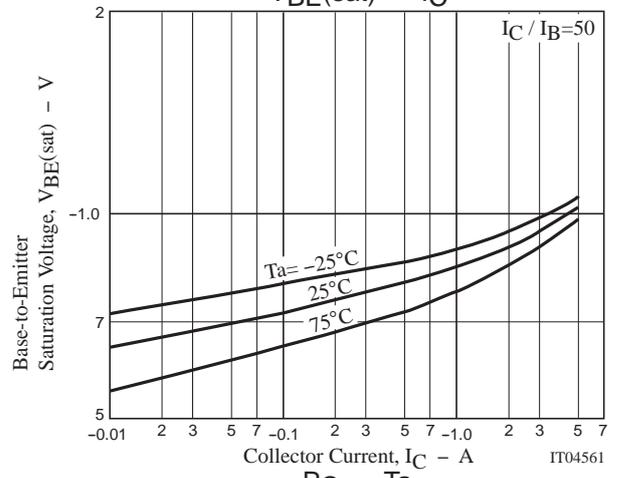
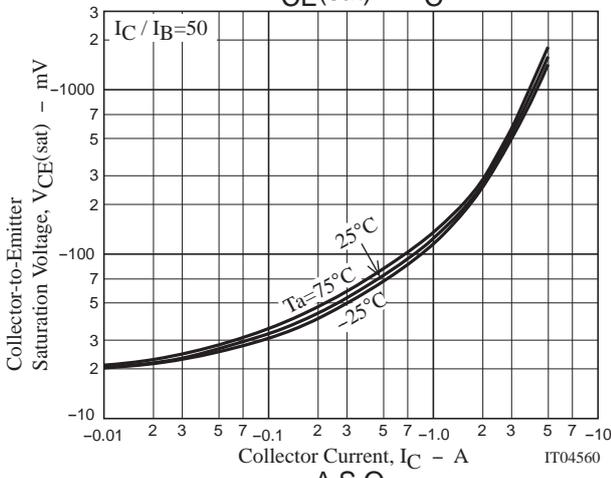
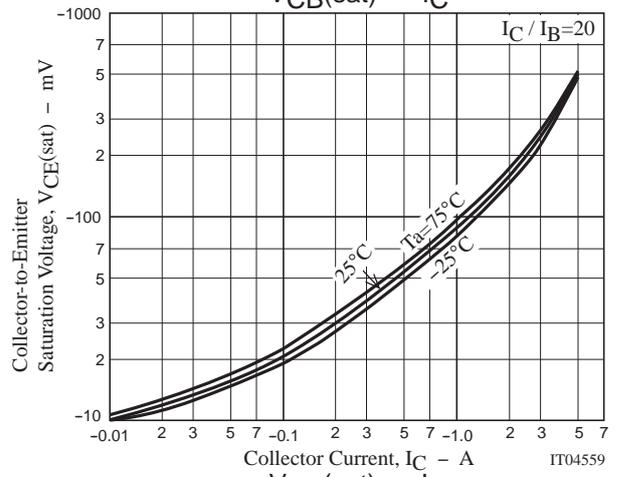
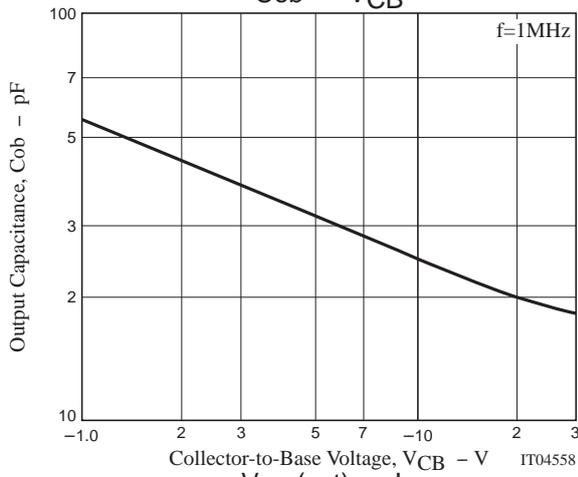
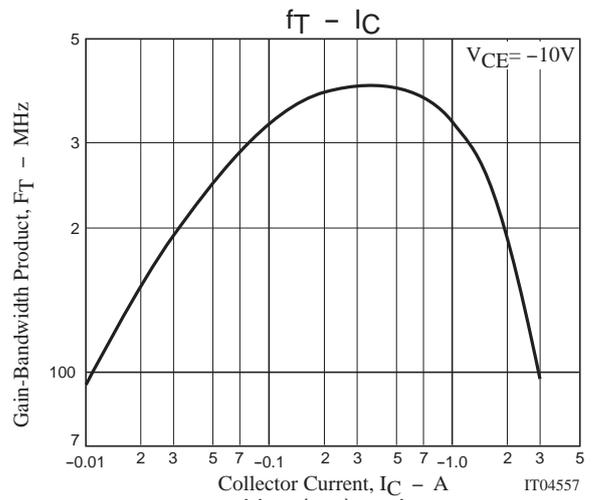
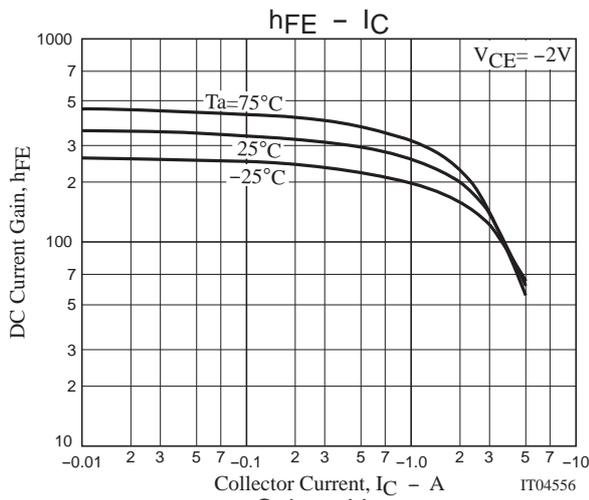
Switching Time Test Circuit



Ordering Information

Device	Package	Shipping	memo
CPH6122-TL-E	CPH6	3,000pcs./reel	Pb Free





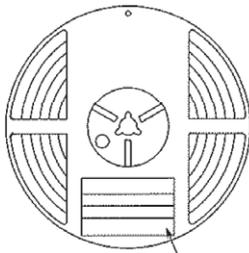
Embossed Taping Specification

CPH6122-TL-E

1. Packing Format

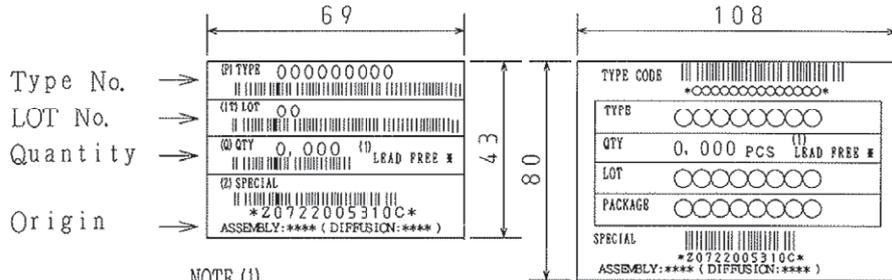
Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
CPH6	CPH6	3,000	15,000	90,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Packing method



Reel label

Reel label, Inner box label (unit:mm) Outer box label
It is a label at the time of factory shipments. The form of a label may change in physical distribution process.



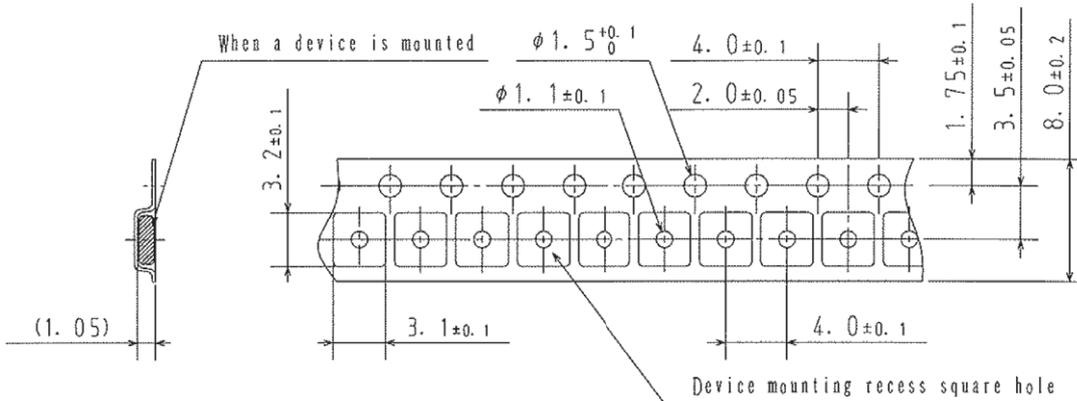
NOTE (1)

The LEAD FREE # description shows that the surface treatment of the terminal is lead free.

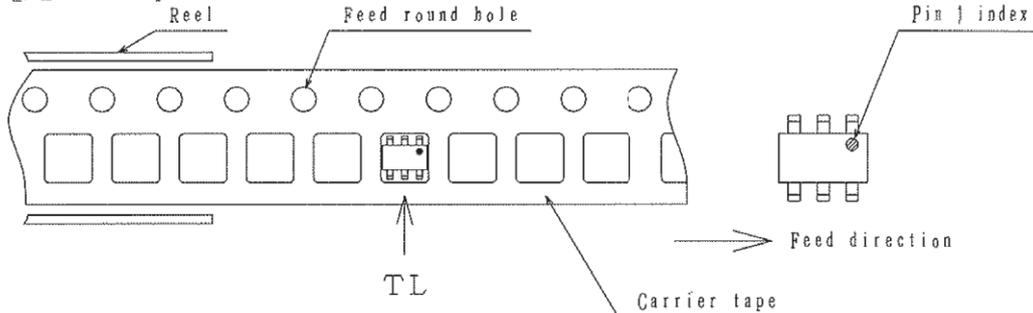
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)



2-2. Device placement direction



Those with pin 1 index on the feed hole side.....TL

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